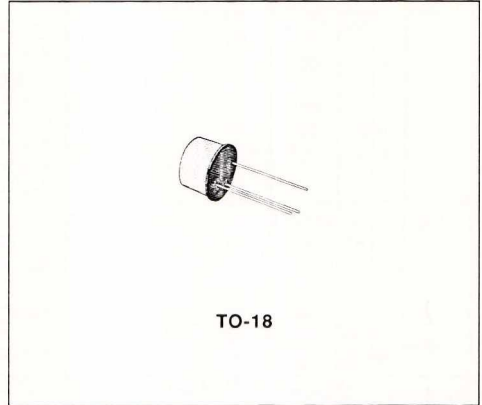


## LOW NOISE AUDIO AMPLIFIERS

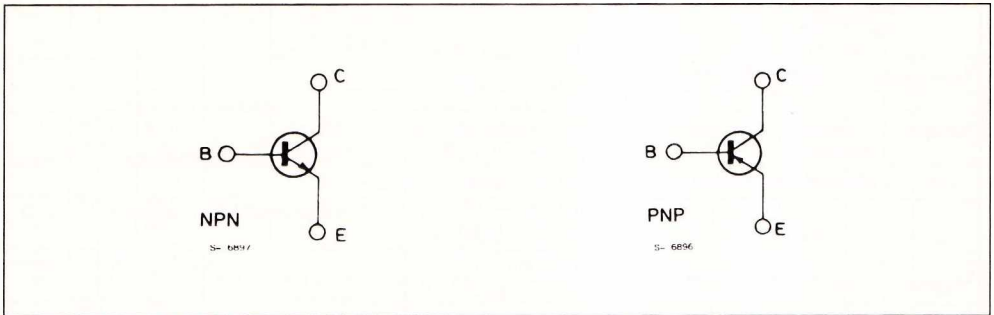
### DESCRIPTION

The BCY78 and BCY79 are silicon planar epitaxial PNP transistors in Jedec TO-18 metal case. They are designed for use in audio driver and low-noise input stages.

The complementary NPN types are respectively the BCY58 and BCY59.



### INTERNAL SCHEMATIC DIAGRAM



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		BCY78	BCY79	
$V_{CES}$	Collector-emitter Voltage ( $V_{BE} = 0$ )	- 32	- 45	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	- 32	- 45	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	- 5		V
$I_C$	Collector Current	- 200		mA
$I_B$	Base Current	- 20		mA
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25^\circ\text{C}$ at $T_{case} \leq 45^\circ\text{C}$	390 1		mW W
$T_{stg}, T_j$	Storage and Junction Temperature	- 65 to 200		$^\circ\text{C}$

THERMAL DATA

$R_{th(j-case)}$	Thermal Resistance Junction-case	Max	150	°C/W
$R_{th(j-amb)}$	Thermal Resistance Junction-ambient	Max	450	°C/W

ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ °C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cutoff Current ( $V_{BE} = 0$ )	For <b>BCY78</b> $V_{CE} = -25\text{ V}$ $V_{CE} = -32\text{ V}$ $V_{CE} = -25\text{ V}$ $T_{amb} = 150\text{ °C}$ For <b>BCY79</b> $V_{CE} = -35\text{ V}$ $V_{CE} = -45\text{ V}$ $V_{CE} = -35\text{ V}$ $T_{amb} = 150\text{ °C}$		-2	-20 -100 -10	nA nA μA
$I_{CEX}$	Collector Cutoff Current ( $V_{BE} = 0.2\text{ V}$ )	For <b>BCY78</b> $V_{CE} = -32\text{ V}$ $T_{amb} = 100\text{ °C}$ For <b>BCY79</b> $V_{CE} = -45\text{ V}$ $T_{amb} = 100\text{ °C}$			-20	μA
$I_{EBO}$	Emitter Cutoff Current ( $I_C = 0$ )	$V_{EB} = -4\text{ V}$			-20	nA
$V_{(BR)CES}$	Collector-emitter Breakdown Voltage ( $V_{BE} = 0$ )	$I_C = -10\text{ μA}$ For <b>BCY78</b> For <b>BCY79</b>	-32 -45			V V
$V_{(BR)CEO}^*$	Collector-emitter Breakdown Voltage ( $I_B = 0$ )	$I_C = -2\text{ mA}$ For <b>BCY78</b> For <b>BCY79</b>	-32 -45			V V
$V_{(BR)EBO}$	Emitter-base Breakdown Voltage ( $I_C = 0$ )	$I_E = -1\text{ μA}$	-5			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = -10\text{ mA}$ $I_B = -0.25\text{ mA}$ $I_C = -100\text{ mA}$ $I_B = -2.5\text{ mA}$		-0.12 -0.4	-0.25 -0.8	V V
$V_{BE}^*$	Base-emitter Voltage	$I_C = -10\text{ μA}$ $V_{CE} = -5\text{ V}$ $I_C = -2\text{ mA}$ $V_{CE} = -5\text{ V}$ $I_C = -10\text{ mA}$ $V_{CE} = -1\text{ V}$ $I_C = -100\text{ mA}$ $V_{CE} = -1\text{ V}$	-0.6	-0.55 -0.65 -0.68 -0.75	-0.75	V V V V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = -10\text{ mA}$ $I_B = -0.25\text{ mA}$ $I_C = -100\text{ mA}$ $I_B = -2.5\text{ mA}$	-0.6 -0.7	-0.7 -0.85	-0.85 -1.2	V V

\* Pulsed : pulse duration = 300 μs. duty cycle = 1 %.

## ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
$h_{FE}^*$	DC Current Gain	$I_C = -10 \mu A$ $V_{CE} = -5 V$	Gr.VII		140		
			Gr.VIII	30	200		
			Gr.IX	40	270		
		$I_C = -2 mA$ $V_{CE} = -5 V$	Gr.VII	120	170	220	
			Gr.VIII	180	250	310	
			Gr.IX	250	350	460	
		$I_C = -10 mA$ $V_{CE} = -1 V$	Gr.VII	80	180		
			Gr.VIII	120	260	400	
			Gr.IX	160	360	630	
		$I_C = -100 mA$ $V_{CE} = -1 V$	Gr.VII	40			
Gr.VIII	45						
Gr.IX	60						
For BCY78 Only	Gr.X						
$I_C = -0.01 mA$ $V_{CE} = -5 V$		100	340				
$I_C = -2 mA$ $V_{CE} = -5 V$		380	500	630			
$I_C = -10 mA$ $V_{CE} = -1 V$		240	500	1000			
$I_C = -100 mA$ $V_{CE} = -1 V$		60					
$h_{fe}$	Small Signal Current Gain	$I_C = -2 mA$ $V_{CE} = -5 V$ $f = 1 kHz$	Gr.VII	125	200	250	
			Gr.VIII	175	260	350	
			Gr.IX	250	330	500	
		for BCY78 Only	Gr.X	350	520	700	
$f_T$	Transition Frequency	$I_C = -10 mA$ $V_{CE} = -5 V$ $f = 100 MHz$		180		MHz	
$C_{EBO}$	Emitter-base Capacitance	$I_C = 0$ $V_{EB} = -0.5 V$ $f = 1 MHz$		11	15	pF	
$C_{CBO}$	Collector-base Capacitance	$I_E = 0$ $V_{CB} = -10 V$ $f = 1 MHz$		4.5	7	pF	
NF	Noise Figure	$I_C = -0.2 mA$ $V_{CE} = -5 V$ $R_g = 2 k\Omega$ $f = 1 kHz$		2	6	dB	
$h_{ie}$	Input Impedance	$I_C = -2 mA$ $V_{CE} = -5 V$ $f = 1 kHz$	Gr.VII	2.7		k $\Omega$	
			Gr.VIII	3.6		k $\Omega$	
			Gr.IX	4.5		k $\Omega$	
		For BCY78 Only	Gr.X	7.5		k $\Omega$	
$h_{re}$	Reverse Voltage Ratio	$I_C = -2 mA$ $V_{CE} = -5 V$ $f = 1 kHz$	Gr.VII	$1.5 \times 10^{-4}$			
			Gr.VIII	$2 \times 10^{-4}$			
			Gr.IX	$2 \times 10^{-4}$			
		For BCY78 Only	Gr.X	$3 \times 10^{-4}$			

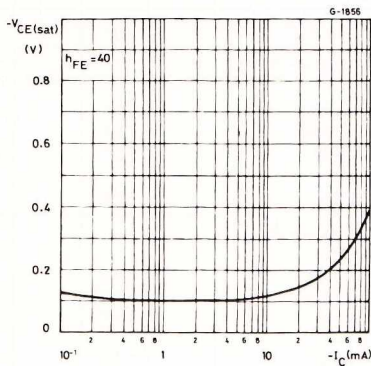
\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle = 1 %.

ELECTRICAL CHARACTERISTICS (continued)

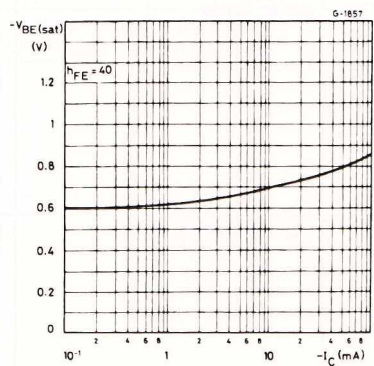
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$h_{oe}$	Output Admittance	$I_C = -2 \text{ mA}$ $V_{CE} = -5 \text{ V}$ $f = 1 \text{ kHz}$ Gr.VII Gr.VIII Gr.IX For <b>BCY78</b> Only Gr.X		18 24 30 50	30 50 60 100	$\mu\text{S}$ $\mu\text{S}$ $\mu\text{S}$ $\mu\text{S}$
$t_d$	Delay Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -10 \text{ mA}$		35 5		ns ns
$t_r$	Rise Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -10 \text{ mA}$		50 50		ns ns
$t_s$	Storage Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -10 \text{ mA}$		400 250		ns ns
$t_f$	Fall Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -10 \text{ mA}$		80 200		ns ns
$t_{on}$	Turn-on Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -10 \text{ mA}$		85 55	150 150	ns ns
$t_{off}$	Turn-off Time	$I_C = -10 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -1 \text{ mA}$ $I_C = -100 \text{ mA}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -10 \text{ mA}$		480 450	800 800	ns ns

\* Pulsed : pulse duration = 300  $\mu\text{s}$ , duty cycle = 1 %.

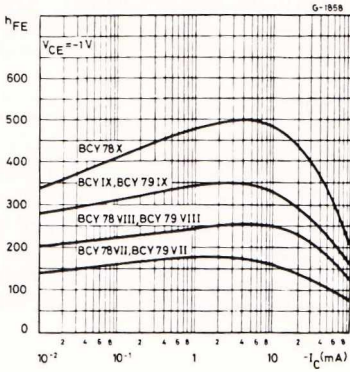
Collector-emitter Saturation Voltage.



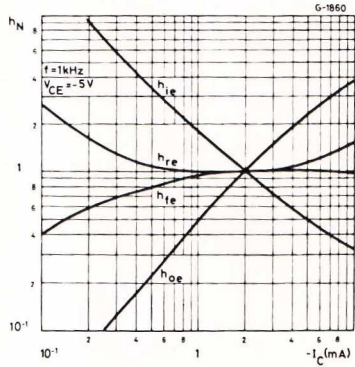
Base-emitter Saturation Voltage.



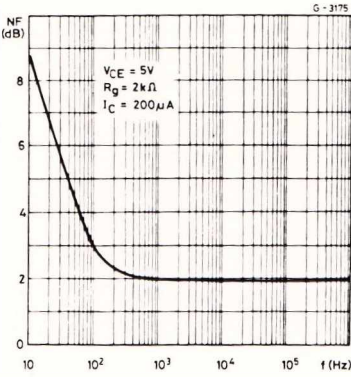
DC Current Gain.



Normalized h Parameters.



Noise Figure vs. Frequency.



Noise Figure ( $f = 1$  kHz).

